

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an ad experson

January 2001



FDC6312P

Dual P-Channel 1.8V PowerTrench[®] Specified MOSFET

General Description

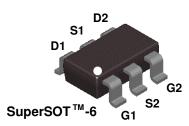
These P-Channel 1.8V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain low gate charge for superior switching performance.

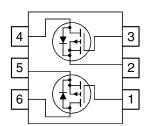
Applications

- Power management
- Load switch

Features

- $\label{eq:rescaled} \begin{array}{l} \bullet \ -2.3 \ \text{A}, \ -20 \ \text{V}. \ \ \text{R}_{\text{DS(ON)}} = 115 \ \text{m}\Omega \ @ \ \text{V}_{\text{GS}} = -4.5 \ \text{V} \\ \\ \text{R}_{\text{DS(ON)}} = 155 \ \text{m}\Omega \ @ \ \text{V}_{\text{GS}} = -2.5 \ \text{V} \\ \\ \text{R}_{\text{DS(ON)}} = 225 \ \text{m}\Omega \ @ \ \text{V}_{\text{GS}} = -1.8 \ \text{V} \end{array}$
- + High performance trench technology for extremely low $\rm R_{\rm DS(ON)}$
- SuperSOTTM-6 package: small footprint (72% smaller than standard SO-8); low profile (1mm thick)





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		-20	V
V _{GSS}	Gate-Source Voltage		±8	V
ID	Drain Current – Continuous	(Note 1a)	-2.3	A
	- Pulsed		-7	
P _D	Power Dissipation for Single Operation	(Note 1a)	0.96	W
		(Note 1b)	0.9	
		(Note 1c)	0.7	
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	130	°C/W
R _{θJC}	Thermal Resistance, Junction-to-Case	(Note 1)	60	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
.312	FDC6312P	13"	12mm	3000 units

©2001 Fairchild Semiconductor Corporation

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted Symbol Min Max Units Parameter **Test Conditions** Тур **Off Characteristics** Drain-Source Breakdown Voltage $V_{GS} = 0 V, I_D = -250 \mu A$ -20 V Breakdown Voltage Temperature $I_D = -250 \ \mu A$, Referenced to $25^{\circ}C$ -11 mV/°C Coefficient Zero Gate Voltage Drain Current $V_{\text{DS}} = -16 \text{ V}, \quad V_{\text{GS}} = 0 \text{ V}$ -1 μA Gate-Body Leakage, Forward $V_{GS} = 8 V$, $V_{DS} = 0 V$ 100 nA $V_{GS} = -8 V$, $V_{DS} = 0 V$ Gate-Body Leakage, Reverse -100nA On Characteristics (Note 2) $V_{DS} = V_{GS}, I_D = -250 \ \mu A$ Gate Threshold Voltage -0.4 -0.9 -1.5 V Gate Threshold Voltage $I_D = -250 \ \mu A$, Referenced to $25^{\circ}C$ 2 mV/∘C **Temperature Coefficient** Static Drain-Source $V_{GS} = -4.5 V$, $I_{D} = -2.3 \text{ A}$ 92 115 mΩ **On-Resistance** $I_{D} = -1.9 \text{ A}$ $V_{GS} = -2.5 V$, 116 155 $V_{GS} = -1.8 V$, $I_{D} = -1.6 \text{ A}$ 225 166 V_{GS} =-4.5 V, I_D =-2.3A, T_J =125°C 112 150 $V_{GS} = -4.5 V$, $V_{DS} = -5 V$ **On-State Drain Current** -7 А Forward Transconductance $V_{DS} = -5 V$, $I_{D} = -3.5 \text{ A}$ 5.3 S **Dynamic Characteristics** pF Input Capacitance 467 $V_{DS} = -10 V$, $V_{GS} = 0 V$, **Output Capacitance** f = 1.0 MHz 85 pF **Reverse Transfer Capacitance** 38 pF Switching Characteristics (Note 2) Turn-On Delay Time 8 16 $V_{DD} = -10 V$, $I_{D} = -1 A$. ns $V_{GS} = -4.5 V$, $R_{GEN} = 6 \Omega$ 23 Turn-On Rise Time 13 ns 32 Turn-Off Delay Time 18 ns Turn-Off Fall Time 8 16 ns **Total Gate Charge** $V_{\text{DS}} = -10 \ V,$ $I_D = -2.3 A$, 4.4 7 nC $V_{GS} = -4.5 V$ Gate-Source Charge 1.0 nC Gate-Drain Charge 0.8 nC **Drain–Source Diode Characteristics and Maximum Ratings** Maximum Continuous Drain-Source Diode Forward Current -0.8 А Drain-Source Diode Forward $V_{GS} = 0 V$, $I_{S} = -0.8 A$ (Note 2) -0.7 -1.2٧ Voltage

Notes:

Is

 V_{SD}

BV_{DSS}

 ΔBV_{DSS}

 ΔT_{J}

IDSS

IGSSF

I_{GSSR}

 $V_{GS(th)}$

 $\Delta V_{GS(th)}$

 $\Delta T_{\rm J}$

R_{DS(on)}

I_{D(on)}

g_{FS}

 C_{iss}

Coss

 C_{rss}

t_{d(on)}

 $t_{d(off)}$

tr

tf

Qg

Q_{gs}

 Q_{gd}

1. ReLA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

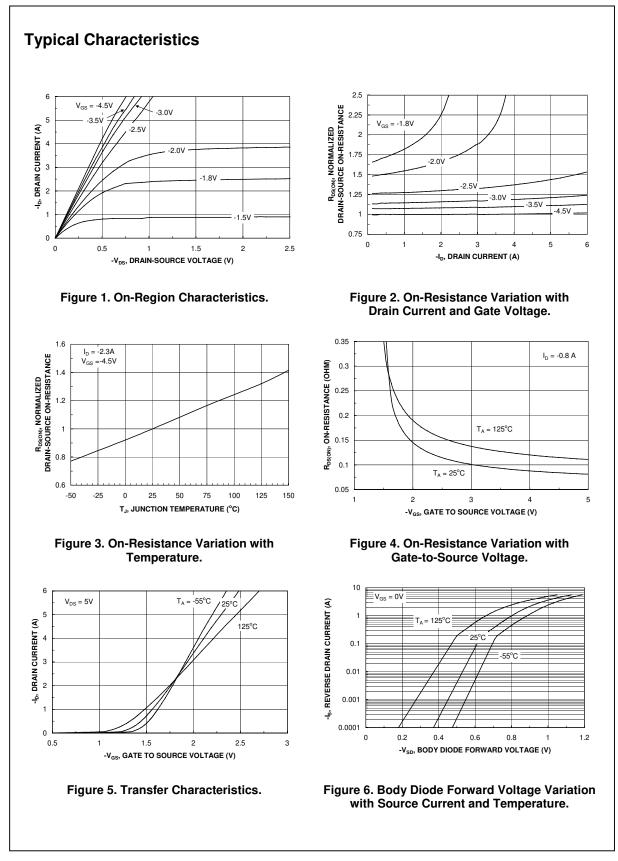
Scale 1:1 on letter size paper

b) 140°/W when mounted on a .004 in² pad of 2 oz copper

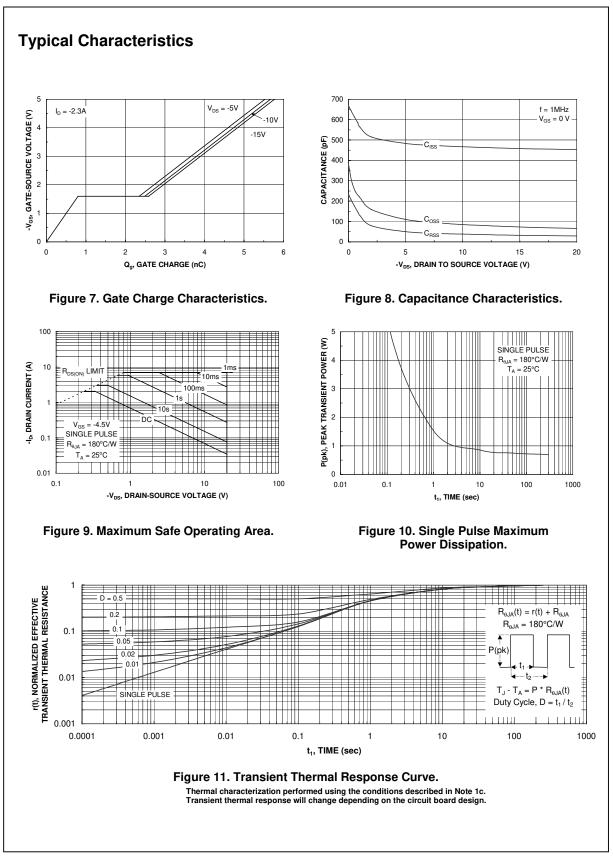
c) 180°/W when mounted on a minimum pad.

FDC6312P Rev C (W)

FDC6312P



FDS6312P



FDS6312P

FDC6312P Rev C (W)

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™ Bottomless™ CoolFET™ *CROSSVOLT*™ DenseTrench™ DOME™ **EcoSPARK™** E²CMOS[™] EnSigna™ FACT™ FACT Quiet Series[™] FAST ® FASTr™ FRFET™ GlobalOptoisolator[™] POP[™] GTO™ HiSeC™ ISOPLANAR™ LittleFET™ MicroFET™ MicroPak™ MICROWIRE™

OPTOLOGIC™ OPTOPLANAR™ PACMAN™ Power247™ PowerTrench[®] QFET™ OS™ QT Optoelectronics[™] Quiet Series[™] SILENT SWITCHER®

SMART START™ VCX™ STAR*POWER™ Stealth™ SuperSOT™-3 SuperSOT[™]-6 SuperSOT[™]-8 SyncFET™ TinyLogic™ TruTranslation™ UHC™ UltraFET[®]

STAR*POWER is used under license

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY. FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS. NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Product Status	Definition
Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.
	Formative or In Design First Production Full Production

Rev. H4

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative